Measurement of the temperature dependence of dwell time and spin relaxation probability of Rb atoms on paraffin surfaces using a beam-scattering method

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The scattering of Rb atoms on an antirelaxation coating was studied. No significant change in the spin relaxation probability of Rb atoms by single scattering from a tetracontane surface was observed by cooling the film from 305 to 123 K. The mean surface dwell time was estimated using a time-resolved method. Delay-time spectra, from which mean surface dwell times can be estimated, were measured at 305, 153, and 123 K, with a time window of 9.3×10^{-5} s. The increase in mean surface dwell time with cooling from 305 to 123 K was smaller than 4.4×10^{-6} s, which is significantly smaller than the value expected from the mean dwell time at room temperature measured using the Larmor frequency shift. These results can be explained by assuming a small number of scattering components, with a mean surface dwell time at least three orders of magnitude longer than the majority component.

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I. INTRODUCTION

Antirelaxation coatings are used to reduce the spin relaxation of alkali-metal atoms resulting from wall collisions in the alkali-metal vapor cells of atomic clocks [1–3] and atomic magnetometers [4–6]. Paraffin [7,8], octadecyltrichlorosilane (OTS) [9,10], and polydimethylsiloxane (PDMS) [11] are representative materials for antirelaxation coatings. It has been reported that paraffin-coated surfaces can support 10⁴ spinpreserving collisions for Rb atoms [8]. The performance of an antirelaxation coating depends on the surface dwell time, as well as the strength of the interaction between alkali-metal spins and the surface. The mean dwell time τ_s can be described by the Arrhenius formula:

$$\tau_{\rm s} = \tau_0 \exp\left(\frac{E_{\rm des}}{k_{\rm B}T_{\rm s}}\right),\tag{1}$$

where τ_0 is the preexponential factor, E_{des} is the desorption energy, k_B is Boltzmann's constant, and T_s is the temperature of the surface. In the case of Rb atoms on tetracontane (C₄₀H₈₂), which is a representative type of paraffin, the experimentally obtained desorption energy is 0.06 eV [12,13]. By adopting a commonly used assumption, i.e., that the preexponential factor is 1×10^{-12} s, which is the typical period of thermal vibration of atoms, we can roughly estimate τ_s as 1×10^{-11} s at 300 K. However, using the Larmor frequency shift, Ulanski and Wu reported a mean dwell time of (1.8 ± 0.2) $\times 10^{-6}$ s for Rb atoms on paraffin coatings at 345 K [14]. The reason for the large difference in the mean dwell time calculated from the desorption energy compared to that measured by experiments is still unclear [15]. One possibility is that the assumption $\tau_0 \simeq 1 \times 10^{-12}$ s is incorrect. By substituting $E_{des} = 0.06$ eV, $T_s = 345$ K, and $\tau_s = 1.8 \times 10^{-6}$ s into Eq. (1) and regarding τ_0 as a variable, we obtain $\tau_0 = 2.4 \times 10^{-7}$ s. However, this is two orders of magnitude larger than the preexponential factor $\tau_0 = 2.2 \times 10^{-9}$ s of ⁸⁷Rb atoms on Pyrex glass surfaces coated with OTS, estimated from the temperature dependence of the mean dwell time [16], and is five orders of magnitude larger than the typical period of thermal vibration. Therefore, this issue requires further investigation.

Equation (1) shows that the mean dwell time increases with cooling, which makes it easier to measure dwell times using time-resolved methods. If we assume that $\tau_0 = 2.4 \times 10^{-7}$ s (which is obtained by substituting $E_{des} = 0.06$ eV [12,13], $\tau_s = 1.8 \times 10^{-6}$ s, and $T_s = 345$ K [14]) is correct, then it can be seen from Eq. (1) that τ_s will increase by 6.7×10^{-5} s with cooling a sample from 305 to 123 K, which is sufficient time to detect using time-resolved methods. The spin relaxation probability with surface scattering is also expected to increase at low temperatures due to increased dwell time.

In this study, we investigate the temperature dependence of the spin relaxation probability and dwell time of Rb atoms on tetracontane coatings. A beam-scattering method and x-ray photoelectron spectroscopy (XPS) were employed to analyze the surface dwell time and surface chemical composition. Using an atomic beam and optical hyperfine pumping, the dwell time can be measured more directly compared to the methods used in earlier studies [14,16]. The results show that the increase in mean dwell time (averaged over the whole time spectra) with cooling from 305 to 123 K is shorter than 4.4×10^{-6} s, which is significantly shorter than the value of 6.7×10^{-5} s expected from the previously reported

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FIG. 1. (a) Schematic illustration of the experimental setup and (b) the energy-level diagram of ⁸⁵Rb.

desorption energy $E_{\text{des}} = 0.06 \text{ eV} [12,13]$ and the mean dwell time $\tau_{\text{s}} = 1.8 \times 10^{-6} \text{ s}$ at 345 K [14]. This indicates the existence of minor scattering components with dwell times at least three orders of magnitude larger than that of the major component.

II. EXPERIMENT

Figure 1(a) shows the experimental setup. A tetracontanecoated quartz substrate was mounted in an ultrahigh-vacuum (UHV) chamber with a base pressure lower than 3×10^{-7} Pa. The tetracontane film was deposited on the substrate in another high-vacuum chamber, the base pressure of which was 1.0×10^{-5} Pa, by evaporating tetracontane at 513 K for 10 min. The thickness and average roughness R_a of the film were measured to be $0.93 \pm 0.17 \,\mu\text{m}$ and 50 nm, respectively, using atomic force microscopy. The Rb beam was generated using a multichannel effusive atomic beam source which consists of a Rb reservoir and an array of capillaries made of stainless steel through which Rb atoms are introduced into the UHV chamber [17]. The multichannel array consists of 30 capillaries with a length, inner diameter, and outer diameter of 68, 0.34, and 0.50 mm, respectively. The FWHM of the atomic beam at the position of the sample was estimated to be 8.2 mm from a fluorescence image taken with a CCD camera. The atomic beam contains both ⁸⁵Rb and ⁸⁷Rb with a natural abundance ratio (7:3), and we pumped and probed only ⁸⁵Rb. The interaction between the two isotopes was negligible under current experimental conditions.

The two pump light beams were directed perpendicular to the Rb beam. The pump and probe frequencies are shown in Fig. 1(b). The optical system used to generate the pump and probe light is illustrated in Fig. 2(a). The frequency of the first pump light was tuned to the $F = 3 \rightarrow F' = 3$ transition frequency of the 85 Rb D_1 transition line using polarization spectroscopy [18,19], where F and F' are the total angular momentum of atoms in the $5^2S_{1/2}$ and $5^2P_{1/2}$ states, respectively. The intensity and the $1/e^2$ full width of the first pump light were 0.5 mW and 7.5 mm, respectively. The second pump light, the frequency of which was tuned to the $F = 2 \rightarrow$ F' = 3 transition frequency of the D_1 line, was generated by blue detuning the first pump light by 3036 MHz [20,21] using an electro-optic modulator and an acousto-optic modulator (AOM) and was pulsed with a pulse duration of 5×10^{-6} s by the AOM. The second pump light was condensed in the direction perpendicular to the surface by a cylindrical lens. Its peak power and $1/e^2$ full width along the direction parallel to the film surface were 4 mW and 7.5 mm. Its orientation was adjusted to be parallel to the sample surface while maintaining perpendicularity to the atomic Rb beam.

The probe light was used to selectively excite Rb atoms in the F = 3 state to the F'' = 4 state through the D_2 transition, resulting in fluorescence. Here, F'' is the total angular momentum of the atoms in the $5^2 P_{3/2}$ state. The fluorescence was detected by a CCD camera and a photomultiplier tube (PMT), which were equipped with interference filters that were designed to transmit only the probe light and fluorescence. The probe light was condensed in the direction perpendicular to the surface by a cylindrical lens. Its intensity and the $1/e^2$ full width along the direction parallel to the film surface were 0.5 mW and 1.0 mm, respectively. Its orientation was parallel to the sample surface. The frequency of the probe light could be tuned, which enabled selective excitation of the incident or scattered atoms. For probing scattered atoms, the probe light was blue detuned from the $F = 3 \rightarrow F'' = 4$ transition frequency of the D_2 transition line by 160 MHz, such that it did not excite incident atoms. With this frequency, the probe light excites Rb atoms whose velocity component along the probe light is 125 ± 5 m/s; these are abundant among scattered atoms [22] but negligible among incident atoms. Here, the natural linewidth of the Rb D_2 transition line (6.06 MHz) [23] was used to calculate the uncertainty. When probing the incident atoms, the direction of the probe light beam was the same as that used to probe the scattered atoms; however, the frequency was red detuned by 60.3 MHz from the





Function generator



FIG. 2. (a) Schematic diagram of the optical system for generating pump and probe light. AOM, EOM, BS, PBS, NPBS, RM, and QWP denote the acousto-optic modulator, electro-optic modulator, beam splitter, polarizing beam splitter, nonpolarizing beam splitter, removable mirror, and quarter-wave plate, respectively. (b) Schematic diagram of the signal-processing system used for the delay-time measurements. (c) Timing diagram of the delay-time measurement.

 $F = 3 \rightarrow F'' = 4$ transition frequency. With this frequency, the probe light excites atoms with a velocity component along the probe light of -47 ± 5 m/s. Because atoms with this velocity component are found among both incident and scattered atoms, the fluorescence intensity of the incident atoms was estimated by subtracting the contribution of scattered atoms from the measured fluorescence intensity, as discussed below.

Mean-dwell-time estimates were based on time-of-flight (TOF) measurements obtained using the pump and probe light. The incident Rb atoms were first pumped to the F = 2 state by the first pump light and subsequently irradiated with the second pump light, which was pulsed; atoms that were irradiated with the second pump light were momentarily pumped to the F = 3 state. The incident atoms pumped to the F = 3 state by the second pump light enhanced the fluorescence induced by the probe light when they reached it. The delay time in the fluorescence enhancement induced by irradiation by the second pump light is the sum of the TOF of the Rb atoms (from the second pump light to the probe light via the film surface) and the surface dwell time. The probe-light-induced fluorescence was detected by the PMT. The signal from the PMT was processed using the system shown in Fig. 2(b). Delay times were obtained by measuring the time intervals between the irradiation of the second pump light and the detection of fluorescence, as shown in Fig. 2(c). Each delay-time spectrum was obtained by accumulating the delay times measured for 2×10^6 shots, which took approximately 30 min.

This method is similar to the method used in Ref. [24], which utilized evanescent waves as pump and probe beams to exclude the contribution of the time of flight. However, our method differs from their method in that the pump and probe light do not illuminate the surface, thus preventing lightinduced phenomena such as light-induced atomic desorption. Also, while Ref. [24] utilized an atomic vapor cell, our method utilizes an atomic beam, which enables us to independently control the surface temperature and the flux intensity of incident atoms, while in the case of vapor cells the impinging rate of atoms depends on the cell temperature.

The delay-time distribution can be treated as the distribution of the sum of the TOF and the dwell time only when the hyperfine relaxation by a single collision is negligibly small. When the hyperfine relaxation by a single collision is significant, hyperfine polarization of incident atoms is lost over the surface dwell time. In this case, a large percentage of the scattered atoms experiences spin relaxation while on the surface; as such, they do not contribute to the delay-time spectra. Therefore, the probability of spin relaxation resulting from surface scattering must be estimated prior to measurement of the dwell time.

To evaluate the spin relaxation resulting from a single collision, we used the first pump light and the probe light. The first pump light polarizes incident Rb atoms in the beam to the F = 2 state. Given that the probe-light-induced fluorescence of the incident and scattered atoms reflects the number of atoms in the F = 3 state, the fluorescence intensity decreases when the first pump light is introduced. The population fraction f_i of the F = 2 state of the incident atoms pumped by the first pump light can be written as

$$f_{\rm i} = \frac{N_2}{N_2 + N_3} \tag{2}$$

$$=1-\frac{N_3}{N},$$
(3)

where N_2 and N_3 are the numbers of atoms in the F = 2and F = 3 states in the incident atoms, respectively, and $N = N_2 + N_3$. Because the fluorescence intensity is proportional to the number of atoms in the F = 3 state,

$$N_3 = CI_{i,p},\tag{4}$$

where *C* is a constant and $I_{i,p}$ is the intensity of the fluorescence of incident atoms induced by the first pump light. $I_{i,p}$ can be obtained by

$$I_{i,p} = i_{-60.3 \text{ MHz},p} - i_{160 \text{ MHz},p} \frac{M(-47 \text{ m/s}, T_s)}{M(125 \text{ m/s}, T_s)},$$
 (5)

where $i_{\delta,p}$ is the fluorescence intensity measured with the first pump light introduced with the probe light blue detuned by δ from the $F = 3 \rightarrow F'' = 4$ transition frequency and $M(v, T_s)$ is the Maxwell distribution, given by

$$M(v, T_{\rm s}) = \sqrt{\frac{2m}{\pi k_{\rm B} T_{\rm s}}} \exp\left(-\frac{mv^2}{2k_{\rm B} T_{\rm s}}\right),\tag{6}$$

where *m* is the mass of an 85 Rb atom. The first term in Eq. (5) includes contributions from both incident and scattered atoms. To subtract the latter, the second term is introduced. The second term is the fluorescence intensity of the scattered atoms excited by the probe light red detuned by 60.3 MHz estimated from the fluorescence intensity measured with the probe light blue detuned by 160 MHz (based on the fact that the velocity distribution of the scattered atoms can be expressed as a Maxwell distribution [22]).

Because F = 2 and F = 3 states have five- and sevenfold degeneracy, N_3 and N can be written as

$$N = \frac{12}{7} C I_{\rm i,np}.\tag{7}$$

Here, $I_{i,np}$ is the intensity of the fluorescence of incident atoms without the first pump light, which can be obtained by

$$I_{i,np} = i_{-60.3 \text{ MHz,np}} - i_{160 \text{ MHz,np}} \frac{M(-47 \text{ m/s}, T_{s})}{M(125 \text{ m/s}, T_{s})}, \quad (8)$$

where $i_{\delta,np}$ is the intensity of fluorescence measured with the probe light blue detuned by δ with the first pump light blocked. Therefore, we can experimentally determine f_i as

$$f_{\rm i} = 1 - \frac{7}{12} \frac{I_{\rm i,p}}{I_{\rm i,np}}.$$
(9)

Similarly, the population fraction f_s of the F = 2 state of the scattered atoms is written as

$$f_{\rm s} = 1 - \frac{7}{12} \frac{I_{\rm s,p}}{I_{\rm s,np}},\tag{10}$$

where $I_{s,p}$ and $I_{s,np}$ are the intensities of the fluorescence of the scattered atoms measured with the probe light blue detuned by 160 MHz with and without the pump light, respectively. The fluorescence of the incident atoms is negligible when the probe laser is blue detuned by 160 MHz, which was confirmed by the fluorescence intensity being lower than the detection limit when the sample was removed from the atomic-beam position. By comparing f_i and f_s , the proportion of atoms whose total angular momentum is changed by scattering at the surface can be estimated.

The delay-time and spin relaxation measurements were conducted using different samples prepared by the same procedure to minimize aggregation of Rb atoms, which may



FIG. 3. X-ray photoelectron spectroscopy spectra of the clean sample and the sample exposed to an Rb beam at 153 K for 2 h and 123 K for 2 h.

contaminate the surface. The aggregation of Rb on the surface resulting from atomic Rb beam irradiation was checked by XPS using Al $K\alpha$ radiation with a photon energy of 1486.6 eV.

III. RESULTS AND DISCUSSION

A. X-ray photoelectron spectroscopy

Aggregation of Rb atoms on the surface was investigated by XPS. The temperature at which aggregation was noticeable was approximately 123 K; this varied slightly among samples. Figure 3 shows the XPS spectra of the as-prepared sample and the spectra taken after exposing the sample to an atomic Rb beam with a flux of $10^{11}-10^{12}$ s⁻¹ at 153 K for 2 h and 123 K for 2 h. The spectrum of the as-prepared sample displayed a strong peak at $E - E_F = -285$ eV, which was assigned to the C 1s state. After exposure to the Rb beam at low temperature, new peaks appeared at $E - E_F = -531$, -246, -238, and -109 eV; these were assigned to the O 2p, Rb $3p_{1/2}$, Rb $3p_{3/2}$, and Rb 3d states, respectively. The existence of the O 2p peak indicates that some of the adsorbed Rb atoms had become oxidized by the residual O₂ or H₂O in the UHV chamber.

B. Spin relaxation resulting from surface scattering

The spin relaxation caused by surface scattering was evaluated at 305, 153, and 123 K. The temperature of the Rb oven of the Rb beam source was set to 393 K. Under these conditions, the flux intensity was estimated to be $10^{11}-10^{12}$ atoms per second based on the designed value and the fluorescence induced by the probe light. Heating of the film surface by incident Rb atoms is negligibly small due to the small thickness and thus high heat transmission of the film and the low flux intensity of Rb beam. This is supported by a previous study [22], which showed that the temperature of the Rb atoms



FIG. 4. (a) Temperature dependence of the F = 2 population fraction of the incident and scattered atoms, f_i and f_s , respectively, and (b) the temperature dependence of the ratio f_s/f_i of the incident and scattered atoms.

scattered from a tetracontane surface estimated by fitting their velocity distribution with Maxwellian was significantly lower than that of the incident beam temperature and was close to the film temperature (room temperature). This indicates not only that the scattered atoms were in thermal equilibrium with the film surface but also that the surface is not severely heated by Rb beam irradiation. Below 123 K, the number of scattered atoms was significantly lower than that above 123 K, indicating the initiation of Rb atom adsorption at around 123 K, which is consistent with the XPS results. Figure 4(a) shows the population fractions of the F = 2 state for the incident and scattered atoms. Uncertainties in the population fractions were estimated by repeating the measurements three to five times. Because the spin relaxation induced by a single scattering process is negligibly small at room temperature [8], the difference between f_s and f_i at 305 K is attributed to the incident atoms away from the beam center, as opposed to relaxation due to scattering. When measuring the population fraction of the F = 2 state of incident atoms, atoms that pass the edge of the atomic beam are difficult to pump or detect due to the large deviation in velocity direction with respect to the incident atoms in the beam center, which the pump and probe light frequencies are tuned to excite. However, when the probe light is blue detuned to detect only the scattered atoms, atoms that were not pumped can be detected, as surface scattering changes the direction of the translational movement of atoms. The temperature dependence of the ratio of the population fraction of the incident and scattered atoms f_s/f_i is shown in Fig. 4(b); no increase in spin relaxation probability induced by cooling was observed above 123 K within



FIG. 5. Delay-time spectra (a) at 303 K taken with a highintensity Rb beam and long repetition period (b) at 305, 153, and 123 K. Dots with error bars represent the experimental data, and solid lines represent the simulation results.

the experimental error. Given that Rb atoms experience 10^4 collisions before their spins relax [8] in paraffin-coated cells at room temperature, the low spin relaxation probability at 123 K means that the mean dwell time at 123 K is smaller than 10^4 times the mean dwell time at 305 K. Thus, from Eq. (1), $\tau_0 \exp(\frac{E_{des}}{k_{\rm B} \times 123 \text{ K}}) \leq 10^4 \tau_0 \exp(\frac{E_{des}}{k_{\rm B} \times 305 \text{ K}})$. By solving this, we obtain $E_{des} \leq 0.16$ eV, which agrees with $E_{des} = 0.06$ eV from previous reports [12,13]. Here, we assumed that Eq. (1) holds in the measured temperature region. Although the desorption energy is only a factor of ~2 larger than $k_{\rm B}T$ at room temperature, this assumption seems reasonable because, in Ref. [8], the temperature dependence of the spin relaxation time could be explained by assuming that the temperature dependence of surface dwell times follows Arrhenius's formula even at temperatures higher than the highest temperature measured in the present study.

C. Delay-time spectra

Figure 5(a) shows the delay-time spectrum at $T_s = 303$ K. The intervals of the second pump light pulses were 2.00×10^{-4} s. During the measurement, spectra with and without the second pump light were acquired by switching the second pump light repeatedly using a shutter. The delay-time spectrum was obtained by subtracting the latter from the former. For this measurement, the temperature of the Rb oven of the beam source was set to 453 K, which was 60 K higher than that used for the low-temperature measurement, to achieve higher signal intensity. As a result, the signal intensity was enhanced by a factor of ~ 20 . The feature at $0-1.0 \times 10^{-5}$ s is attributed to the second pump light, which partially penetrated the interference filter, and the fluorescence of the incident atoms; this is excluded from the intensity integration discussed below. The time origin was defined by the rising edge of the second pump light-derived feature. The feature peaking at around 2×10^{-5} s was attributed to the enhanced fluorescence of scattered atoms caused by the second pump light. The peak area obtained by integrating the intensity in the region of 1.0×10^{-5} – 1.89×10^{-4} s and subtracting the average level of the region of 1.89×10^{-4} - 1.94×10^{-4} s as the base level, which corresponds to the sum of the area of the regions represented by α and β in Fig. 5(a), accounted for $91\% \pm 5\%$ of the total signal intensity. Here, the total signal intensity is the sum of regions α , β , and γ . If we adopt the average level of the region of 9.3×10^{-5} - 9.8×10^{-5} s as the base level, the integrated intensity in the region of $1.0 \times$ 10^{-5} –9.3 × 10^{-5} s, which corresponds to the area of region α , accounts for 79% \pm 2% of the total intensity. This implies that $79\% \pm 2\%$ of the scattered atoms will contribute to the peak intensity in the delay-time spectra if we regard the sum of the region of $t < 9.3 \times 10^{-5}$ s as the peak intensity and adopt the average level of the region of 9.3×10^{-5} – 9.8×10^{-5} s as the base level. For the temperature-dependence measurement, we used 1.00×10^{-4} s as the second pump light interval and subtracted the average of the region near the back edge of the time window from the whole spectra, instead of subtracting the background spectra taken without the second pump light. This dramatically reduced the measurement time, which was essential to prevent Rb aggregation during measurements at low temperatures.

Figure 5(b) shows the delay-time spectra taken at 305, 153, and 123 K. The temperature of the Rb oven of the Rb beam source was set to 393 K. By cooling the tetracontane film from 305 to 123 K, the delay-time spectrum shifted to the longer side, and the mean delay time $\tau_{\rm M}$ increased by $(7.0 \pm 3.2) \times 10^{-6}$ s from $(2.54 \pm 0.21) \times 10^{-5}$ to $(3.24 \pm 0.24) \times 10^{-5}$ s. Here, $\tau_{\rm M}$ is defined by

$$\pi_{\rm M} = \frac{\sum_i t_i I_i}{\sum_i I_i},\tag{11}$$

where t_i and I_i are the delay time and the intensity at the *i*th point, respectively. The uncertainty in τ_M originates from the uncertainty in I_i at each point, which is $\sqrt{I_i}$. Data points in the region of $6 \times 10^{-6} \le t_i < 9.3 \times 10^{-5}$ s were included in the summation. The average of the region of $9.5 \times 10^{-5} \le t_i < 9.9 \times 10^{-5}$ s was adopted as the base level. Intensities between 0 and 6×10^{-6} s, which include the peak originating from the second pump light, were not included in the summation. Because the velocity distribution of the scattered beam also depends on the film temperature [22], we cannot simply attribute the increase in τ_M to the increase in mean dwell time. To evaluate the increase in TOF due to the change in velocity distribution, we simulated TOF spectra without taking the dwell time into account.

The simulation considered the TOF from the second pump light to the surface and from the surface to the probe light. The longitudinal velocity distribution $d_b(v)$ of the incident atoms and the TOF distribution from the second pump light to the surface $D_b(t, L_1)$ were calculated using [22]

$$d_{\rm b}(v) = \frac{m^2}{2k_{\rm B}^2 T_{\rm b}^2} v^3 \exp\left(-\frac{mv^2}{2k_{\rm B}T_{\rm b}}\right),\tag{12}$$

$$D_{\rm b}(t,L_1) = d_{\rm b}\left(\frac{L_1}{t}\right) \frac{d}{dt} \left(\frac{L_1}{t}\right) \tag{13}$$

$$= \frac{m^2 L_1^4}{2k_{\rm B}^2 T_{\rm b}^{2} t^5} \exp\left[-\frac{m}{2k_{\rm B} T_{\rm b}} \left(\frac{L_1}{t}\right)^2\right], \quad (14)$$

where $T_{\rm b}$ is the temperature of the incident beam determined by the temperature of the capillary of the beam source, v is the velocity of atoms, L_1 is the distance between the second pump light and the surface along the atomic beam direction, and t is the time. $T_{\rm b}$ was 453 K, and L_1 was roughly estimated to be 1.8×10^{-3} m. The distribution $d_{\rm s}(v_{\perp s})$ of the velocity component of the scattered atoms perpendicular to the surface, which are in thermal equilibrium with the film, and the TOF distribution $D_{\rm s}(t, L_2)$ are given by

$$d_{\rm s}(v_{\perp \rm s}) = \sqrt{\frac{2m}{\pi k_{\rm B} T_{\rm s}}} \exp\left(-\frac{m v_{\perp \rm s}^2}{2k_{\rm B} T_{\rm s}}\right),\tag{15}$$

$$D_{\rm s}(t,L_2) = d_{\rm s}\left(\frac{L_2}{t}\right) \frac{d}{dt} \left(\frac{L_2}{t}\right) \tag{16}$$

$$= \sqrt{\frac{2m}{\pi k_{\rm B} T_{\rm s}}} \frac{L_2}{t^2} \exp\left[-\frac{m}{2k_{\rm B} T_{\rm s}} \left(\frac{L_2}{t}\right)^2\right], \quad (17)$$

where $v_{\perp s}$ is the velocity component perpendicular to the film surface and L_2 , which was estimated to be 1.42×10^{-3} m, is the height of the probe light from the film surface [22]. The total TOF spectrum S(t) is given by

$$S(t) = \frac{1}{w} \int_{t-w}^{t} dr \int_{0}^{r} ds \, u_{b}(s, L_{1}) \\ \times u_{s}(r-s, L_{s}),$$
(18)

where

$$u_{\rm b}(t, L_1) = \int_0^\infty \frac{1}{\sqrt{2\pi\sigma_1^2}} \exp\left(-\frac{(x - L_1)^2}{2\sigma_1^2}\right) \\ \times D_{\rm b}(t, x) dx, \tag{19}$$

$$u_{s}(t, L_{2}) = \int_{0}^{\infty} \frac{1}{\sqrt{2\pi\sigma_{2}^{2}}} \exp\left(-\frac{(x - L_{2})^{2}}{2\sigma_{2}^{2}}\right) \times D_{s}(t, x) dx,$$
(20)

where w is the duration of the second pump light and σ_1 and σ_2 are the $1/\sqrt{e}$ half widths of the second pump light and probe light, respectively. ω , σ_1 , and σ_2 were 5×10^{-6} s, 2.4×10^{-4} m, and 1.7×10^{-4} m, respectively.

The simulation results are indicated by solid lines in Fig. 5. The intensities of the simulation results were adjusted to fit the experimental results. The simulated TOF spectra are in good agreement with the experimental results. According to the simulation results at 305 K, the peak area calculated by integrating the spectral intensity between 1.0×10^{-5} and 9.3×10^{-5} s and subtracting the average of the region of 9.3×10^{-5} - 9.8×10^{-5} s accounts for 81% of the total intensity, which is in good agreement with the experimental results shown in Fig. 5(a). The simulated mean TOF calculated from the region of 0–9.3 $\times 10^{-5}$ s increased by 5.8 $\times 10^{-6}$ s from 2.48×10^{-5} to 3.06×10^{-5} s with cooling from 305 to 123 K. Here, the average of the region of $9.5 \times 10^{-5} \leq t_i < 9.9 \times$ 10^{-5} s was adopted as the base level. The experimentally observed shift of $\tau_{\rm M}$, which is $(7.0 \pm 3.2) \times 10^{-6}$ s, is the sum of the increase in mean dwell time and mean TOF. Therefore, the increase in mean dwell time induced by cooling can be obtained by subtracting the increase in the simulated mean TOF from the experimentally obtained increase in the mean delay time. Therefore, we can see from the experimental and simulation results that

$$\tau_{s,t<93\,\mu s} (123 \text{ K}) - \tau_{s,t<93\,\mu s} (305 \text{ K})$$

= $(1.2 \pm 3.2) \times 10^{-6} \text{ s},$ (21)

which means

$$\tau_{s,t<93\,\mu s} (123 \text{ K}) - \tau_{s,t<93\,\mu s} (305 \text{ K}) \leqslant 4.4 \times 10^{-6} \text{ s.}$$
(22)

Here, $\tau_{s,t < t_{max}}(T_s)$ is the mean dwell time of the scattering component, with a delay time of less than t_{max} at a surface temperature of T_s .

D. Discussion

The discrepancy between our result $[\tau_s(123 \text{ K}) - \tau_s(305 \text{ K}) \leq 4.4 \times 10^{-6} \text{ s}]$ and the value $[\tau_s(123 \text{ K}) - \tau_s(305 \text{ K}) = 6.7 \times 10^{-5} \text{ s}]$ obtained by substituting the desorption energy $E_{des} = 0.06 \text{ eV}$ [12,13] and mean dwell time $\tau_s = 1.8 \times 10^{-6} \text{ s}$ at T = 345 K [14] into Eq. (1) may be explained by assuming multiple scattering components with different mean dwell times. Using the method described in this study, scattering components with dwell times larger than 9.3×10^{-5} s are not detected. In Ref. [14], on the other hand, the mean dwell time was estimated based on the Larmor frequency shift caused by the interaction with the surface and evanescent pump light.

The reason for the difference in mean dwell times between the scattering components can be attributed to differences in preexponential factors. It has been reported that a certain proportion of the incident atoms penetrate the PDMS film, diffuse into the bulk, and desorb from the surface [15], which makes the mean dwell time about a million times larger than that calculated from the desorption energy and film temperature. If the diffusion barrier in the bulk is significantly smaller than the desorption energy, the temperature dependence of the diffusion time can be neglected, so that the temperature dependence of the mean dwell time is almost entirely determined by the desorption energy. By assuming that two scattering components with different mean dwell times exist, we can approximate the temperature dependence of the mean dwell time as

$$\tau_{\rm s} = (1-p)\tau_1 \exp\left(\frac{E_{\rm des}}{k_{\rm B}T_{\rm s}}\right) + p\tau_2 \exp\left(\frac{E_{\rm des}}{k_{\rm B}T_{\rm s}}\right), \quad (23)$$

where p is the proportion of scattering events with longer mean dwell times and τ_1 and τ_2 are the preexponential factors for the scattering events with shorter and longer mean dwell times, respectively. We suppose that $\tau_2 \exp(\frac{E_{\text{des}}}{k_0 T})$ is significantly larger than the time window of 9.3×10^{-5} s and only the component with a shorter mean dwell time, which corresponds to the first term in Eq. (23), contributes to the delay-time spectra. By substituting Eq. (1) into our results $[\tau_{\rm s}(123 \text{ K}) - \tau_{\rm s}(305 \text{ K}) \leq 4.4 \times 10^{-6} \text{ s}]$, we obtain $0 < \tau_1 \leq 1.6 \times 10^{-8}$ s. From $\tau_2 \exp(\frac{E_{\rm des}}{k_{\rm B}T_{\rm s}}) \gg 9.3 \times 10^{-5}$ s at $T_{\rm s} \leq$ 305 K, we get $\tau_2 \gg 9.47 \times 10^{-6}$ s. By substituting $\tau_s = 1.8 \times$ 10^{-6} s at 345 K [14] and $E_{des} = 0.06$ eV [12,13] into Eq. (23), $p = \frac{2.4 \times 10^{-7} \text{s} - \tau_1}{\tau_1}$. From $0 < \tau_1$ and $\tau_2 \gg 9.47 \times 10^{-6}$ s, $p < \tau_2 \approx 10^{-6}$ 0.025, which means that the component with a shorter mean dwell time is the major component. This is consistent with the fact that the observed 79% \pm 2% fraction within 9.3 \times 10⁻⁵ s is nearly the same as the 81% fraction obtained from the simulation without dwell times. Because of their small proportion and broad delay-time distribution, it is difficult to resolve the component with a longer mean dwell time with the current method. To resolve it, we need to improve the experimental precision and to enlarge the time window size, which require much longer measurement time. However, because adsorption of Rb on the surface becomes significant after long exposure to the Rb beam at low temperature, we cannot increase the measurement time significantly. Development of techniques to suppress adsorption is desired for further investigation.

IV. CONCLUSIONS

Scattering of Rb atoms on tetracontane surfaces was investigated. No significant spin relaxation was observed with a single scattering process down to 123 K. The temperature evolution of delay time showed that the increase in mean surface dwell time induced by cooling from 305 to 123 K was less than 4.4×10^{-6} s. Taken together, the results indicate the existence of multiple scattering sites. The preexponential factor τ_0 of the minor components is at least three orders of magnitude larger than that of the major component, which means that the mean dwell time of the minor scattering components is at least three orders of magnitude larger than that of the major component has that the mean dwell time of the minor scattering components is at least three orders of magnitude larger than that of the major component.

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Correction: Minor errors in Eqs. (21) and (22) have been fixed.